Power MOSFET 40 V, 17.9 mΩ, 22 A, Single N–Channel

Features

- Low R_{DS(on)} to Minimize Conduction Losses
- Low Q_G and Capacitance to Minimize Driver Losses
- AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T _J = 25° C unless otherwise noted)						
Parameter			Symbol	Value	Unit	
Drain-to-Source Voltage			V _{DSS}	40	V	
Gate-to-Source Voltage			V_{GS}	±20	V	
Continuous Drain Cur-	Steady State	$T_C = 25^{\circ}C$	Ι _D	23	А	
rent $R_{\theta JC}$ (Notes 1 & 3)		$T_C = 100^{\circ}C$		16		
Power Dissipation $R_{\theta JC}$		$T_C = 25^{\circ}C$	PD	18.3	W	
(Note 1)		$T_C = 100^{\circ}C$		9.1		
Continuous Drain		$T_A = 25^{\circ}C$	Ι _D	9.2	А	
Current $R_{\theta JA}$ (Notes 1, 2 & 3)	Steady	$T_A = 100^{\circ}C$		6.5		
Power Dissipation $R_{\theta JA}$ (Notes 1 & 2)	State	$T_A = 25^{\circ}C$	PD	2.9	W	
		$T_A = 100^{\circ}C$		1.5	1	
Pulsed Drain Current	T _A = 25°	C, t _p = 10 μs	I _{DM}	104	А	
Operating Junction and Storage Temperature			T _J , T _{stg}	-55 to 175	°C	
Source Current (Body Diode)			I _S	15	А	
Single Pulse Drain–to–Source Avalanche Energy (T _J = 25°C, I _{L(pk)} = 1.7 A)			E _{AS}	63	mJ	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			ΤL	260	°C	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Junction-to-Case (Drain) (Note 1)	$R_{\theta JC}$	8.2	°C/W
Junction-to-Ambient - Steady State (Note 2)	$R_{\theta JA}$	51.7	

The entire application environment impacts the thermal resistance values shown, 1. they are not constants and are only valid for the particular conditions noted.

2. Surface-mounted on FR4 board using a 650 mm², 2 oz. Cu pad.

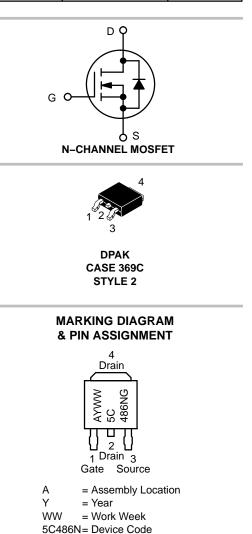
3. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.



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V _{(BR)DSS}	R _{DS(on)}	I _D
40 V	17.9 mΩ @ 10 V	22 A



ORDERING INFORMATION

= Pb-Free Package

G

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

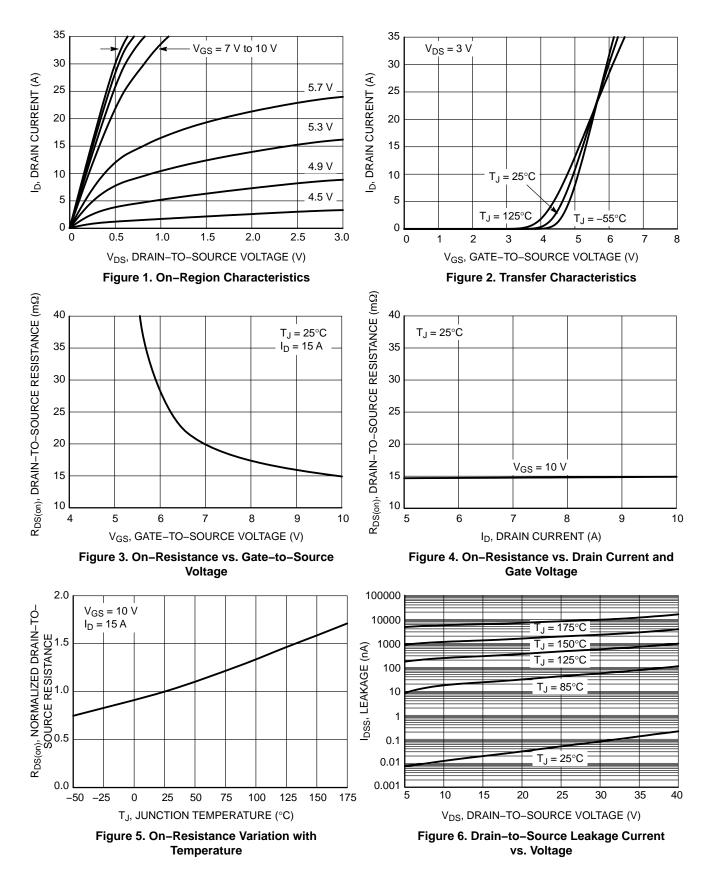
Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V_{GS} = 0 V, I _D = 250 μ A		40			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				16		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	$V_{CS} = 0 V_{c}$	T _J = 25°C			10	μA
		V _{GS} = 0 V, V _{DS} = 40 V	T _J = 125°C			250	
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V _{GS} = 20 V				100	nA
ON CHARACTERISTICS (Note 4)					-		
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D}$	= 20 μA	2.0		4.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				6.1		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = 10 V, I	_D = 10 A		14.9	17.9	mΩ
Forward Transconductance	9 FS	$V_{DS} = 3 V, I_D$) = 10 A		17.5		S
CHARGES, CAPACITANCES AND GATE RE	SISTANCES						•
Input Capacitance	C _{iss}	V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = 25 V			380		pF
Output Capacitance	C _{oss}				200		
Reverse Transfer Capacitance	C _{rss}				15		
Total Gate Charge	Q _{G(TOT)}	V _{GS} = 10 V, V _{DS} = 32 V, I _D = 10 A			14		nC
Threshold Gate Charge	Q _{G(TH)}				2.9		
Gate-to-Source Charge	Q _{GS}				4.3		
Gate-to-Drain Charge	Q _{GD}				2.8		
Plateau Voltage	V _{GP}				4.6		V
SWITCHING CHARACTERISTICS (Note 5)					•		
Turn-On Delay Time	t _{d(on)}				9.0		ns
Rise Time	t _r	$V_{00} = 10 V V_{0}$	-32 V		14		1
Turn–Off Delay Time	t _{d(off)}	V_{GS} = 10 V, V_{DS} = 32 V, I _D = 10 A, R _G = 2.5 Ω			15		
Fall Time	t _f				3.0		
DRAIN-SOURCE DIODE CHARACTERISTIC	S						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 V$, $T_J = 25^{\circ}C$			0.88	1.2	V
		$I_{\rm S} = 10 {\rm A}$	T _J = 125°C		0.77		-
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 \text{ V}, \text{ dls/dt} = 100 \text{ A/}\mu\text{s},$ $I_{S} = 10 \text{ A}$			27		ns
Charge Time	ta				12		1
Discharge Time	tb				15		1
Reverse Recovery Charge	Q _{RR}				10		nC

ORDERING INFORMATION

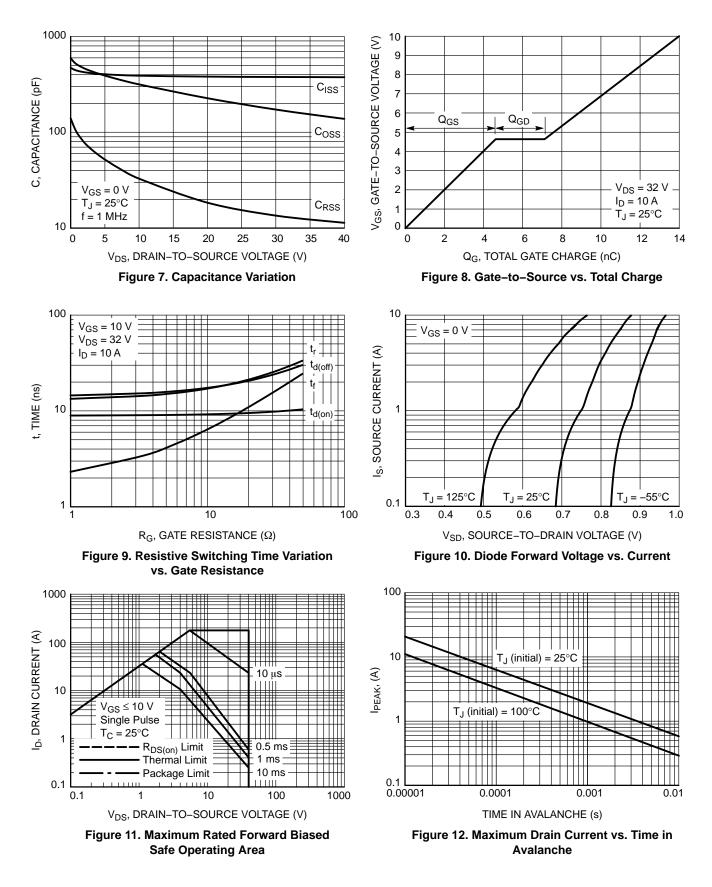
Order Number	Package	Shipping [†]
NVD5C486NT4G	DPAK (Pb–Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

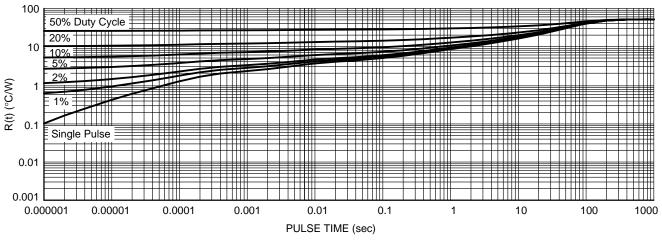
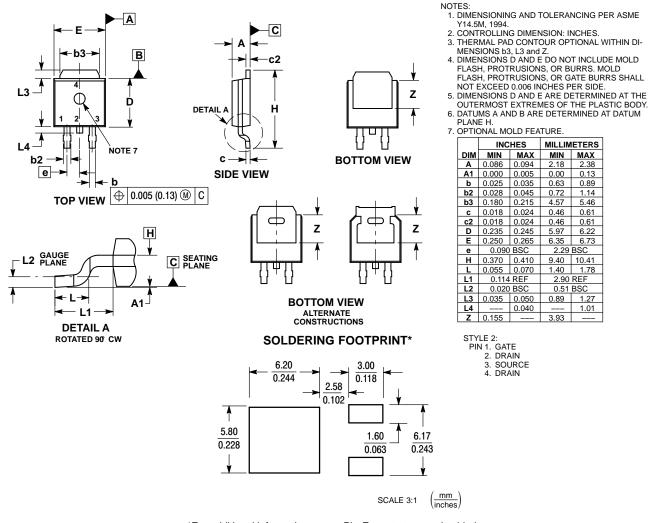


Figure 13. Thermal Characteristics

PACKAGE DIMENSIONS

DPAK (SINGLE GAUGE) CASE 369C

ISSUE F



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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MILLIMETERS

MIN MAX 2.18 2.38

0.13

0.89

1.14

5.46

0.61

0.61

6.22

1.01

2.18

0.00

0.63

0.72

4.57

0.46

5.97

6.35 6.73

2.29 BSC

9.40 10.41

1.40 1.78

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0.094

0.040

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